# ■PRODUCT CLASSIFICATION

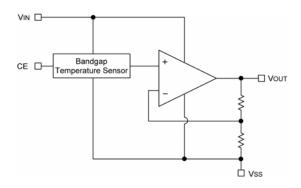
## Ordering Information

### XC31B1234567-8(\*1)

DESIGNATOR	DESCRIPTION	SYMBOL	DESCRIPTION
1	Polarity of Output Voltage	Р	+ (Positive)
2	Temperature Coefficient	N	- (Negative)
34	Output Voltage (25°C)	20~60	e.g. 20=2.0V, 30=3.0V
(5)	Revision Character	A ~	-
		MR	SOT-25
67-8	Packages Taping Type <sup>(*2)</sup>	MR-G	SOT-25
		DR	USP-6B

<sup>(1)</sup> The "-G" suffix indicates that the products are Halogen and Antimony free as well as being fully RoHS compliant.

# **■BLOCK DIAGRAM**



# ■ABSOLUTE MAXIMUM RATINGS

Ta=25°C, Vss=0V

PARAMETER		SYMBOL	RATINGS	UNIT
Input Voltage		Vin	<b>−</b> 0.3 <b>∼</b> 12	V
Output Voltage		Vout	−0.3 <b>~</b> 12	V
CE Pin Voltage		VCE	$-0.3 \sim Vin+0.3$	V
Output Current		lout	20	mA
Power Dissipation	SOT-25	Pd	150	mW
Fower Dissipation	USP-6B	Fu	100	11100
Operating Temperature Range		Topr	−30 ~ +80	လ
Storage Temperature Range		Tstg	<b>−40 ~ +125</b>	°C

The device orientation is fixed in its embossed tape pocket. For reverse orientation, please contact your local Torex sales office or representative. (Standard orientation: ⑥R-⑧ Reverse orientation: ⑥L-⑧)

# **■**ELECTRICAL CHARACTERISTICS

### XC31BPN20A VOUT(T) (\*1) = 2.0V

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Voltage	Vin		1	-	10	V
Output Voltage	Vout	IOUT=100 $\mu$ A $^{(*2)}$ , VIN=4.0V, Ta=25°C	1.94	2.0	2.06	V
Detectable			-30		+80	°C
Temperature Range			-50		+60	C
Output Voltage	Tp (*3)	IOUT=100 μ A, VIN=4.0V	2400	2000	4400	nnm/°C
Temperature Coefficient	ID(°)	-30°C≦Ta≦80°C	-3400	-3900	-4400	ppm/°C
Temperature Sensitivity	Tse	-30°C≦Ta≦80°C	-6.8	-7.8	-8.8	mV/°C
Linearity Margin Error	TL (*4)	-30°C≦Ta≦80°C	-	1	3.5	%
Load Dogulation	ΔVOUT	VIN=4.0V		2.0		mV
Load Regulation	Δ ۷ Ο Ο Ι	1 <i>μ</i> A≦Ιουτ≦100 <i>μ</i> A	_	2.0	_	IIIV
Supply Current 1	Iss1	VIN=VCE=4.0V, Ta=25°C	-	7	17	μΑ
Supply Current 2	Iss2	VIN=4.0V, VCE=Vss, Ta=25°C		_	0.1	μΑ
CE "High" Level Voltage	VCEH		1.5	-	_	V
CE "Low" Level Voltage	VCEL		_	_	0.3	V

### XC31BPN40A VOUT(T) (\*1) =4.0V

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Voltage	Vin		ı	ı	10	V
Output Voltage	Vout	IOUT=100 $\mu$ A $^{(*2)}$ , VIN=6.0V,Ta=25°C	3.88	2.0	4.12	V
Detectable			-30		+80	တိ
Temperature Range			-50		+60	C
Output Voltage Temperature Coefficient	T <sub>D</sub> (*3)	Iouτ=100 μ A, Vin=6.0V -30°C≦Ta≦80°C	-3400	-3900	-4400	ppm/°C
Temperature Sensitivity	Tse	-30°C≦Ta≦80°C	-13.6	-15.6	-17.6	mV/°C
Linearity Margin Error	TL (*4)	-30°C≦Ta≦80°C	_	1	3.5	%
Load Regulation	ΔVоυт	Vin=6.0V 1 μ A≦IouT≦100 μ A	ı	3.0	1	mV
Supply Current 1	ISS1	VIN=VCE=6.0V, Ta=25°C	ı	8	18	μΑ
Supply Current 2	ISS2	VIN=6.0V, VCE=Vss, Ta=25°C	1	-	0.1	μΑ
CE "High" Level Voltage	VCEH		1.5	-	-	V
CE "Low" Level Voltage	VCEL		_	_	0.3	V

#### NOTE

If this IC is to be used in applications where such currents are required, please use a buffer on the output

\*3: Output voltage temperature coefficient (TD) is defined as:

$$T_D = \frac{\Delta V_{OUT}}{T_{a} \cdot V_{OUT}}$$

\*4: Linearity margin error (TL) is calculated as follows:

$$TL = \frac{emax}{Tse \cdot \triangle Ta}$$

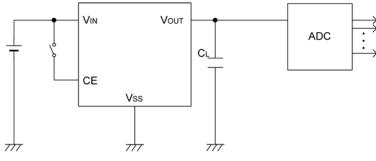
where emax = maximum error.

The maximum error is the maximum difference between the actual measured value and the value on an approximated straight line.

<sup>\*1:</sup> Vout(t) = Specified output voltage at 25°C.

<sup>\*2:</sup> When output current exceed  $100 \,\mu$  A, output voltage drop will increase.

# **■**TYPICAL APPLICATION CIRCUIT



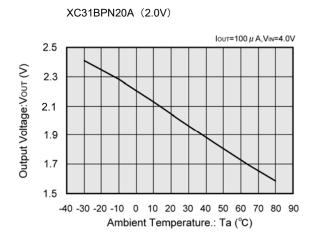
CL :  $0.01 \,\mu\,\text{F}$  (ceramic capacitor)

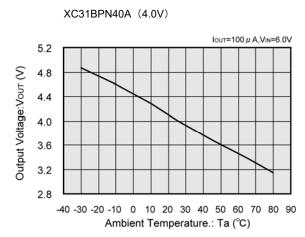
# **■**NOTE ON USE

- 1. When the load capacitance C<sub>L</sub> is too large, oscillation may occur on the output signal.
- 2. Output signal overshoot will occur when the power (VIN) is switched on or when the power drastically fluctuates. The chip enable (CE) function is effective for helping to avoid overshoot and also in saving consumption current.

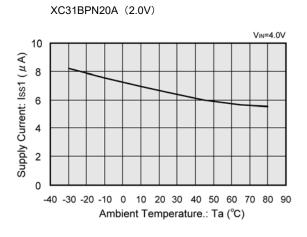
## ■TYPICAL PERFORMANCE CHARACTERISTICS

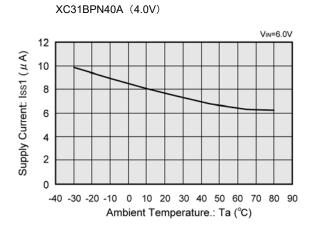
### (1) Output Voltage vs. Ambient Temperature



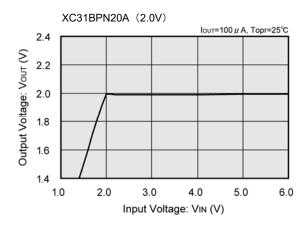


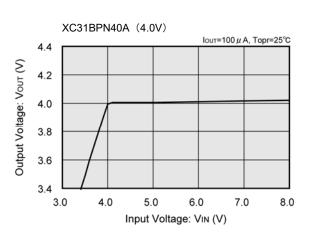
### (2) Supply Current vs. Ambient Temperature





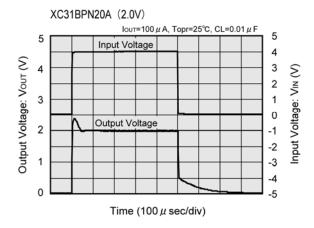
### (3) Output Voltage vs. Input Voltage

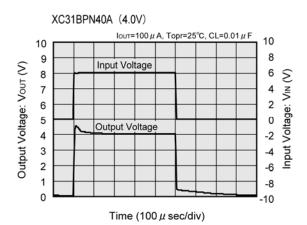




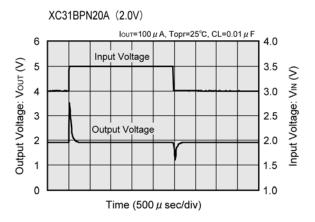
# ■TYPICAL PERFORMANCE CHARACTERISTICS(Continued)

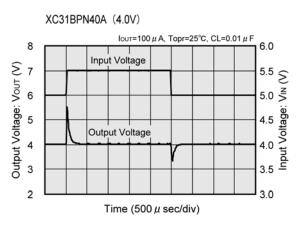
### (4) Input Transient Response 1



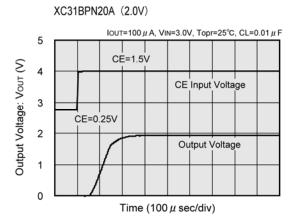


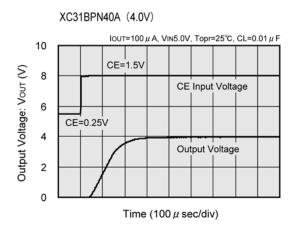
### (5) Input Transient Response 2





## (6) CE Pin Transient Response

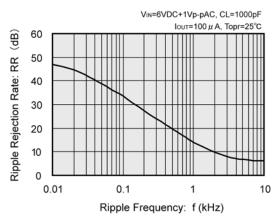




# ■TYPICAL PERFORMANCE CHARACTERISTICS(Continued)

### (7) Ripple Rejection Rate

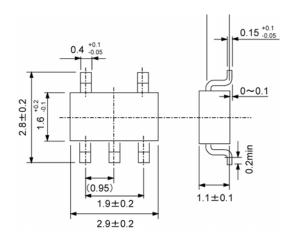


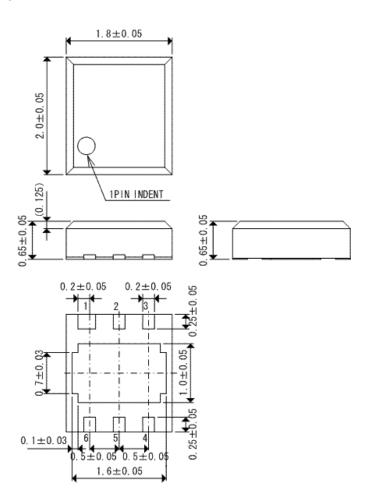


# **■PACKAGING INFORMATION**

## ●SOT-25

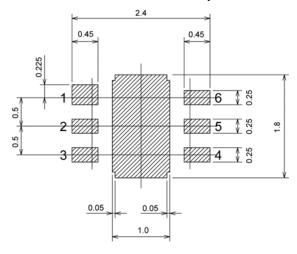
### ●USP-6B



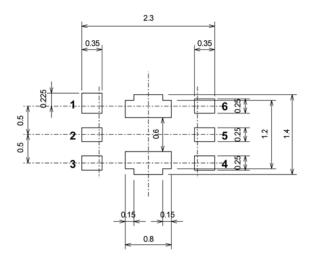


# ■ PACKAGING INFORMATION (Continued)

## ●USP-6B Recommended Pattern Layout

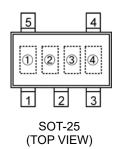


## ●USP-6B Recommended Metal Mask Design



# ■MARKING RULE

#### ●SOT-25



- 1 based on internal standards
- 2 represents integer of output voltage

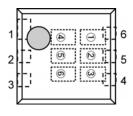
MARK	VOLTAGE (V)	
2	2.x	
3	3.x	
4	4.x	
5	5.x	
6	6.x	

### 3 represents decimal number point of output voltage

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MARK	VOLTAGE (V)			
0	x.0			
1	x.1			
2	x.2			
3	x.3			
4	x.4			
5	x.5			
6	x.6			
7	x.7			
8	x.8			
9	x.9			

(4) represents assembly lot number (Based on internal standards)

### ●USP-6B



USP-6B (TOP VIEW)

### 1 represents polarity of output voltage

MARK	POLARITY	PRODUCT SERIES
Р	+	XC31BPN**AD*

### 2 represents temperature coefficient

MARK	COEFFICIENT	PRODUCT SERIES
N	-	XC31BPN**AD*

### 34 represents output voltage(25°C)

Ex)

MARK		VOLTAGE	PRODUCT SERIES	
3	4	(V)	PRODUCT SERIES	
2	0	2.0	XC31BPN20AD*	
3	0	3.0	XC31BPN30AD*	

### ⑤ represents revision character

Ex)

MARK	PRODUCT SERIES
A	XC31BPN**AD*

6 represents production lot number

0~9, A~Z repeated. (G, I, J, O, Q, W excluded)

\*No character inversion used.

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